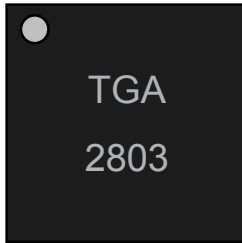
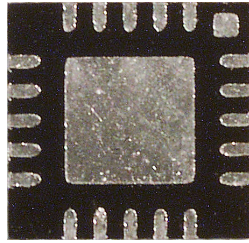


## CATV TIA/Gain Block

## TGA2803-SM



Top View



Bottom View

### Product Description

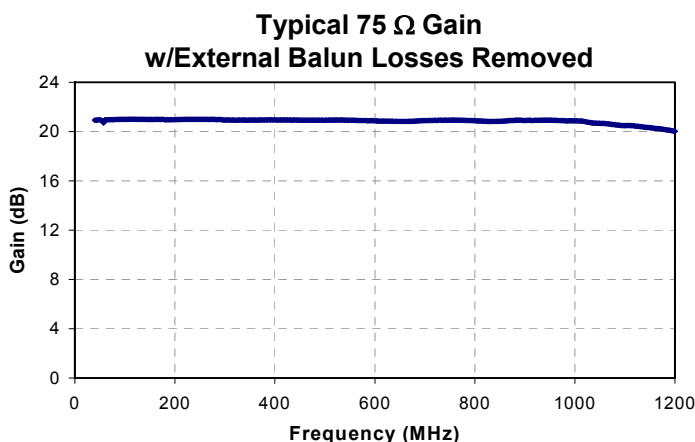
The TriQuint TGA2803-SM is an ultra-linear, packaged TIA/Gain Block which operates from 40MHz to 1000MHz.

The TGA2803-SM typically provides flat gain along with ultra-low distortion. It also provides high output power with low DC power consumption.

This amplifier is ideally suited for use in CATV distribution systems or other applications requiring extremely low noise and distortion.

Demonstration Boards are available.

Lead-free and RoHS compliant.



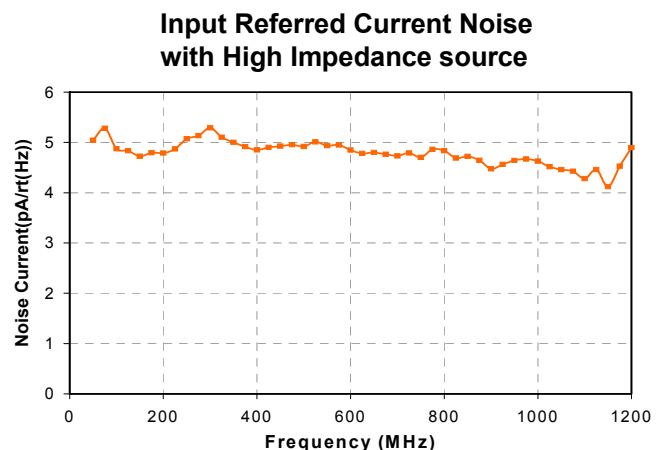
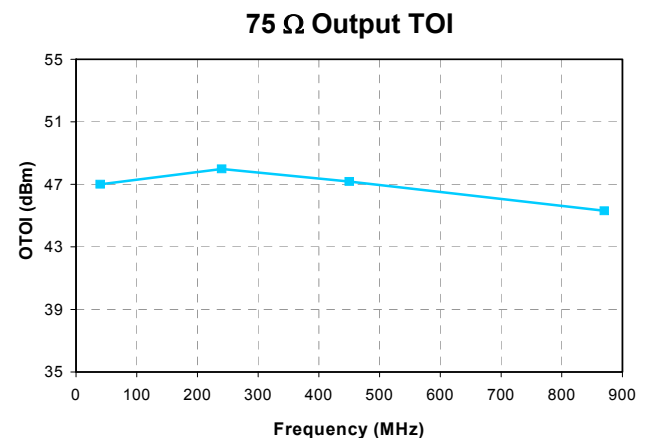
### Key Features and Performance

- Frequency Range: 40MHz - 1GHz
- 20 dB Flat Gain
- 800 Ω Transimpedance \*
- <math><5\text{pA}/\sqrt{\text{Hz}}</math> Equivalent Input Noise Current \*
- 1.5 dB 75 Ω Noise Figure
- Ultra-Low Distortion (45dBm IP3 typ.)
- Low DC Power Consumption
- Single Supply Bias (+8V)
- Proven GaAs Technology
- 20L Package Dimension: 4.0 x 4.0 x 0.9 mm

\* Includes 1:1 balun, No photodiode or auto-transformer

### Primary Applications

- HFC Nodes
- CATV Line Amplifiers
- Head End Equipment



**Table I**  
**Maximum Ratings 1/**

| Symbol            | Parameter                             | Min | Max | Units | Notes               |
|-------------------|---------------------------------------|-----|-----|-------|---------------------|
| V <sub>DD</sub>   | Bias Supply Voltage                   | 0   | 15  | V     |                     |
| I <sub>DD</sub>   | Bias Supply Current                   |     | 500 | mA    | <u>1/</u> <u>2/</u> |
| P <sub>IN</sub>   | RF Input Power                        |     | 77  | dBmV  | <u>3/</u>           |
| T <sub>ASSY</sub> | Assembly Temperature (30 seconds max) |     | 260 | °C    |                     |
| T <sub>CH</sub>   | Channel Temperature                   |     | 150 | °C    |                     |
| T <sub>STG</sub>  | Storage Temperature                   | -65 | 150 | °C    |                     |

1/ These values reflect maximum operable values for this device. Operating above the recommended values may directly affect T<sub>m</sub>.

2/ Total Current

3/ Total Input Power

**Table II**  
**DC Specifications**

| Symbol            | Parameter                       | Typ             | Unit |
|-------------------|---------------------------------|-----------------|------|
| V <sub>DD</sub>   | Bias Supply Voltage             | 8               | V    |
| I <sub>DD</sub>   | Bias Supply Current             | 350             | mA   |
| V <sub>G1</sub>   | Gate 1 Voltage (Pin 19)         | 0.90            | V    |
| V <sub>G2</sub>   | Gate 2 Voltage (Pin 7)          | 2.66            | V    |
| V <sub>out1</sub> | RF Output 1 Voltage (Pin 14/15) | V <sub>DD</sub> | V    |
| V <sub>out2</sub> | RF Output 2 Voltage (Pin 11/12) | V <sub>DD</sub> | V    |

**Table III**  
**RF Specifications 1/**  
 $T_A=25^{\circ}\text{C}$ ,  $V_{DD}=8\text{V}$

| Symbol    | Parameter   | Min | Typ       | Max  | Units    | Note         |
|-----------|---|-----|-----------|------|----------|--------------|
| BW        | Bandwidth   | 40  |           | 1000 | MHz      |              |
| $S_{21}$  | Power Gain  | 17  | 20        | 26   | dB       | <u>2/</u>    |
| GF        | Gain Flatness   |     | $\pm 0.3$ |      | dB       | <u>2/</u>    |
| NF        | Noise Figure  |     | 1.5       |      | dB       | <u>2/</u>    |
| TZ        | Transimpedance  |     | 800       |      | $\Omega$ |              |
| $I_n$     | Equivalent Input Current Noise                              |     | 5         |      | pA/rtHz  | <u>4/</u>    |
| $IP_3$    | Two-Tone, Third-Order Intercept (450 MHz)                   |     | 46        |      | dBm      |              |
| $IP_3$    | Two-Tone, Third-Order Intercept (750 MHz)                   | 39  | 42        |      | dBm      | <u>2/ 3/</u> |
|           | Harmonics ( $2^{nd}$ , $3^{rd}$ , $4^{th}$ ) (40 to 500MHz) |     | -64       | -58  | dBc      | <u>5/</u>    |
| IRL       | Input Return Loss   |     | 16        |      | dB       |              |
| ORL       | Output Return Loss  |     | 20        |      | dB       |              |
| $I_D$     | Drain Current   |     | 350       | 500  | mA       | <u>6/</u>    |
| $P_{sat}$ | Saturated Output Power (750 MHz)                            | 26  | 28        |      | dBm      |              |

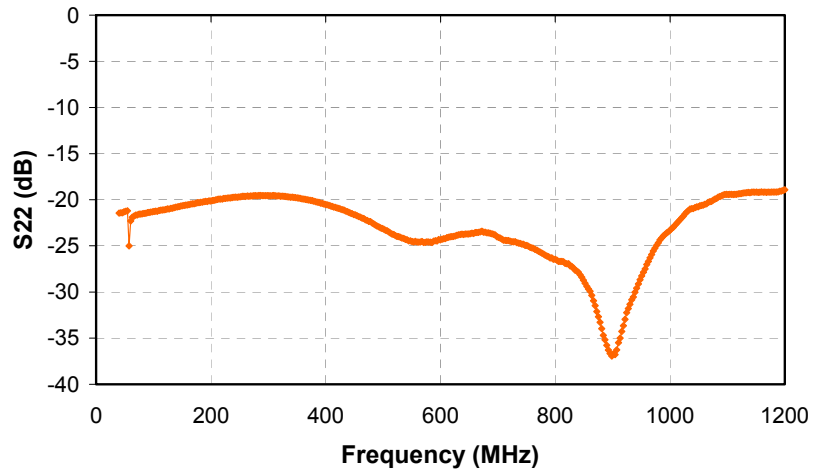
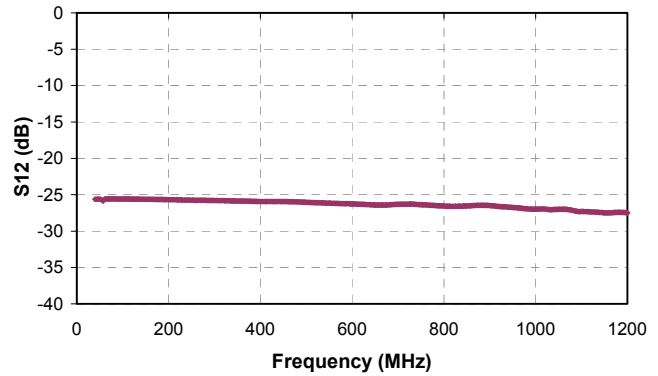
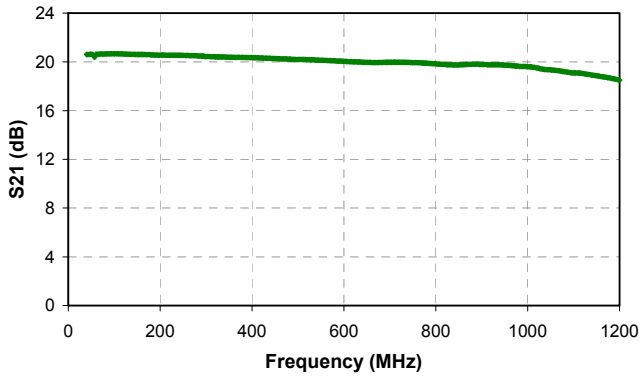
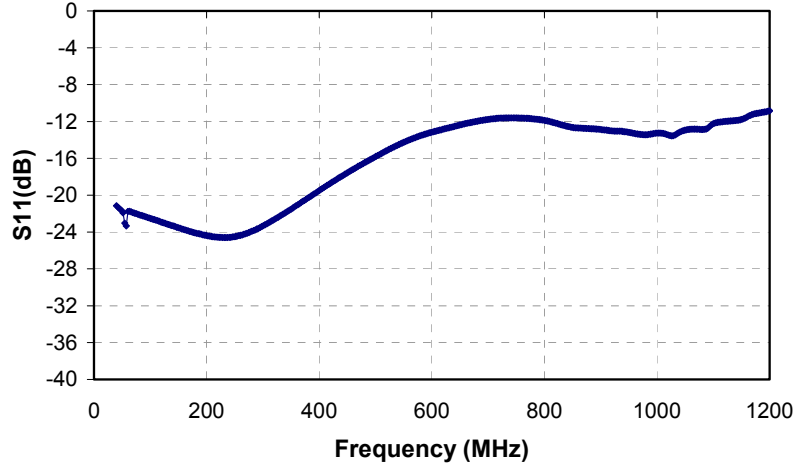
- 1/ Using electrical application circuit on pg. 8  
2/ 1:1 Balun losses have been removed from the measurement  
3/ Measured at 16dBm output power per tone  
4/ Measured with open-circuited input  
5/ Measured at 15dBm fundamental frequency output power  
6/ Increasing drain current will improve linearity of device

**TABLE IV**  
**THERMAL INFORMATION**

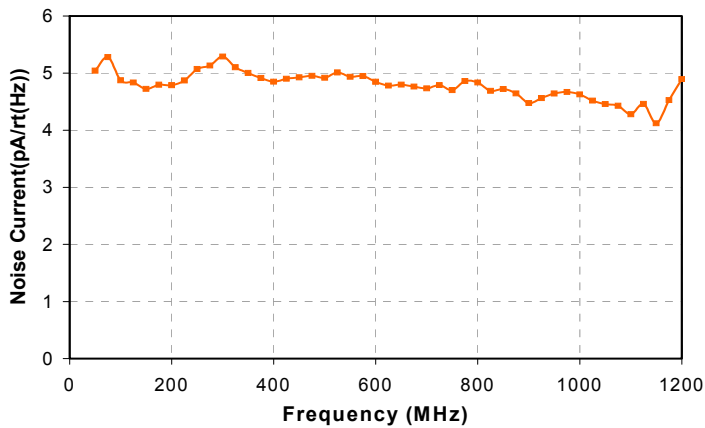
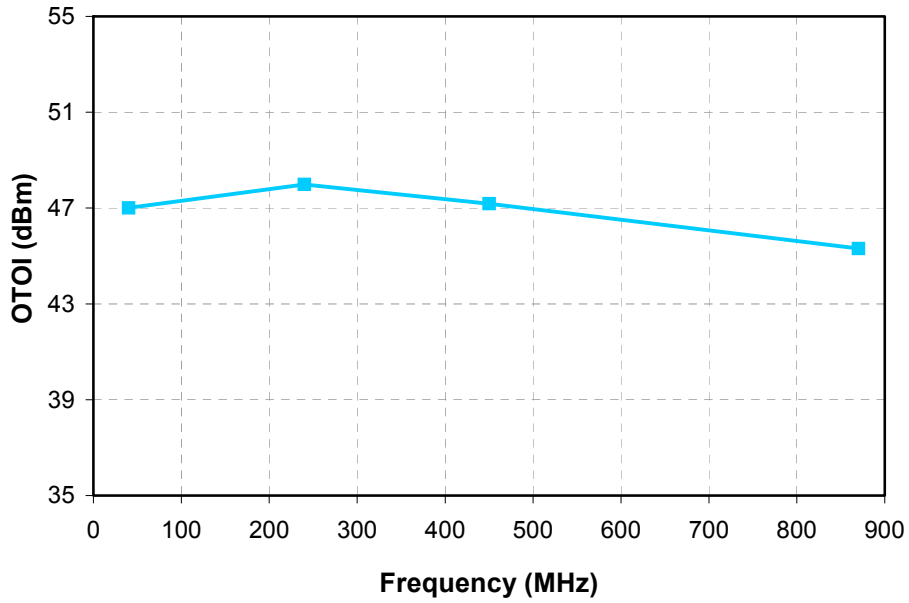
| Parameter   | Test Conditions  | $T_{CH}$<br>( $^{\circ}\text{C}$ ) | $\theta_{JC}$<br>( $^{\circ}\text{C}/\text{W}$ ) | $T_M$<br>(HRS) |
|---|--|------------------------------------|--|----------------|
| $\theta_{JC}$ Thermal Resistance<br>(channel to backside of<br>package) | $V_d = 8\text{ V}$<br>$I_d = 350\text{ mA}$<br>$P_{diss} = 2.8\text{ W}$ | 128                                | 15.4   | 7.2 E+6        |

Note: Worst case condition with no RF applied, 100% of DC power is dissipated. Package backside temperature @ 85  $^{\circ}\text{C}$

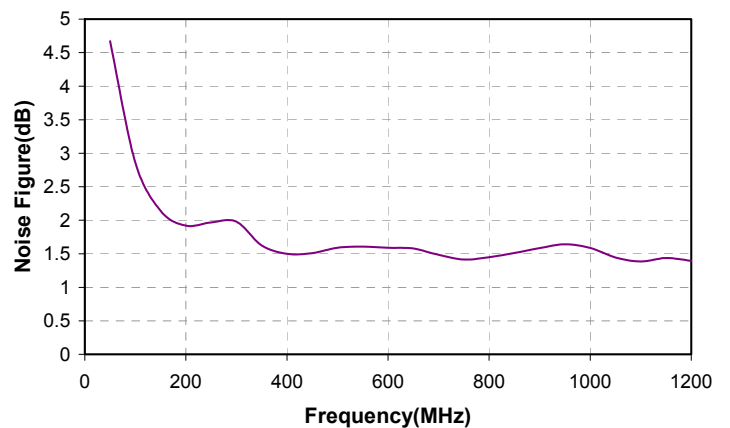
**Typical Measured S-Parameters (75  $\Omega$ )**  
**Using Application Circuit**  
(includes effects of external baluns)



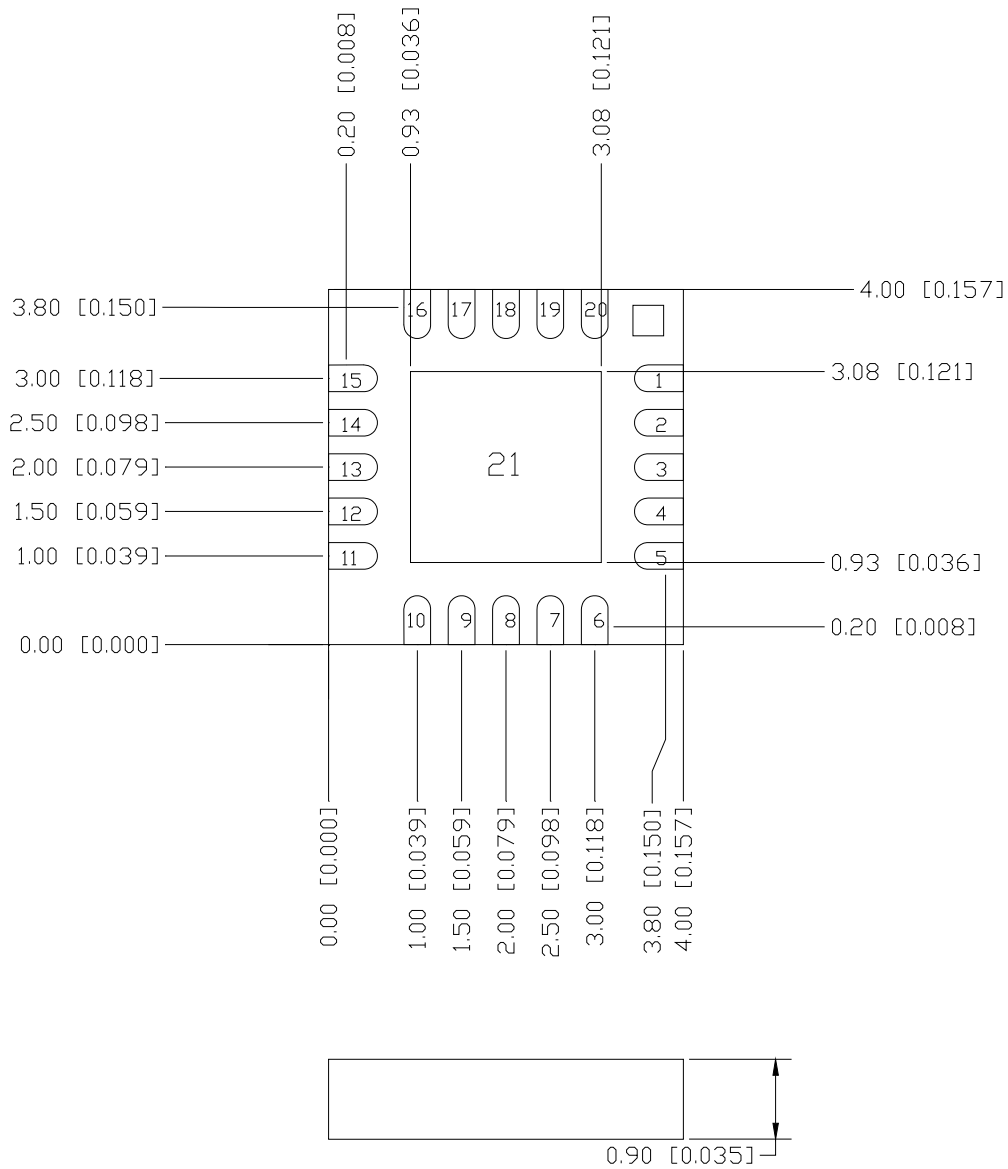
**Typical Measured Performance  
Using Application Circuit**  
(includes effects of external baluns)



**Input balun losses removed**

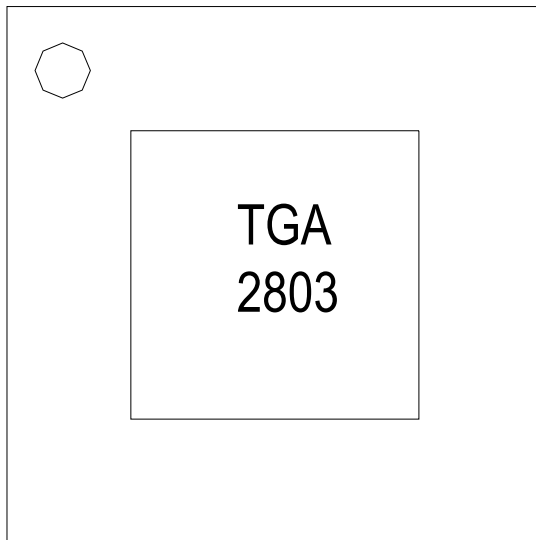


## Mechanical Specifications



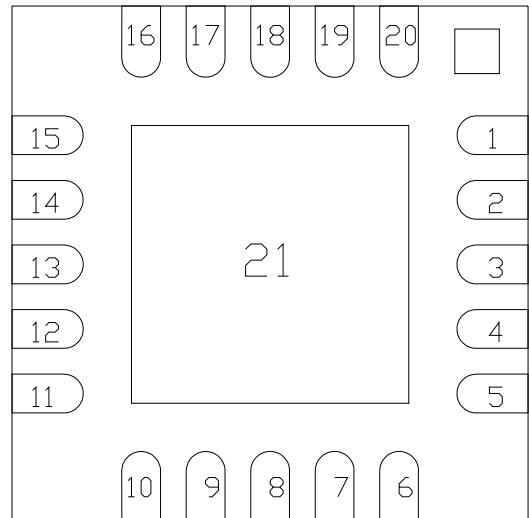
Units: millimeters (inches)  
Package Tolerance +/- 0.10 (0.004)

## Pinout



Top Side

Dot indicates Pin 1



Bottom Side

| Pin | Description                      | Pin    | Description    |
|-----|----------------------------------|--------|----------------|
| 1   | RF Input 1                       | 11     | RF Output 2    |
| 2   | RF Input 1                       | 12     | RF Output 2    |
| 3   | GND                              | 13, 21 | GND            |
| 4   | RF Input 2                       | 14     | RF Output 1    |
| 5   | RF Input 2                       | 15     | RF Output 1    |
| 6   | NC                               | 16     | NC             |
| 7   | VG2 (Optional)                   | 17     | VDD (choked)   |
| 8   | VDD                              | 18     | VDD            |
| 9   | VDD (choked)                     | 19     | VG1 (Optional) |
| 10  | I <sub>sense</sub> <sup>1/</sup> | 20     | NC             |

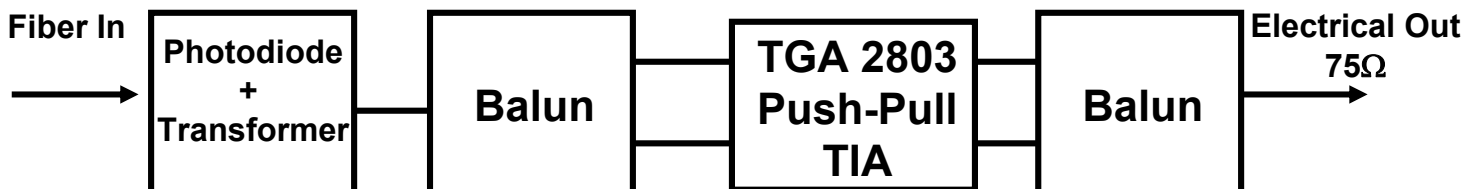
<sup>1/</sup> Bias current monitor:  $I_{sense} = (\text{Voltage}_{pin 10}) / 4\Omega$

## Application Diagrams

### Electrical Gain Amplifier

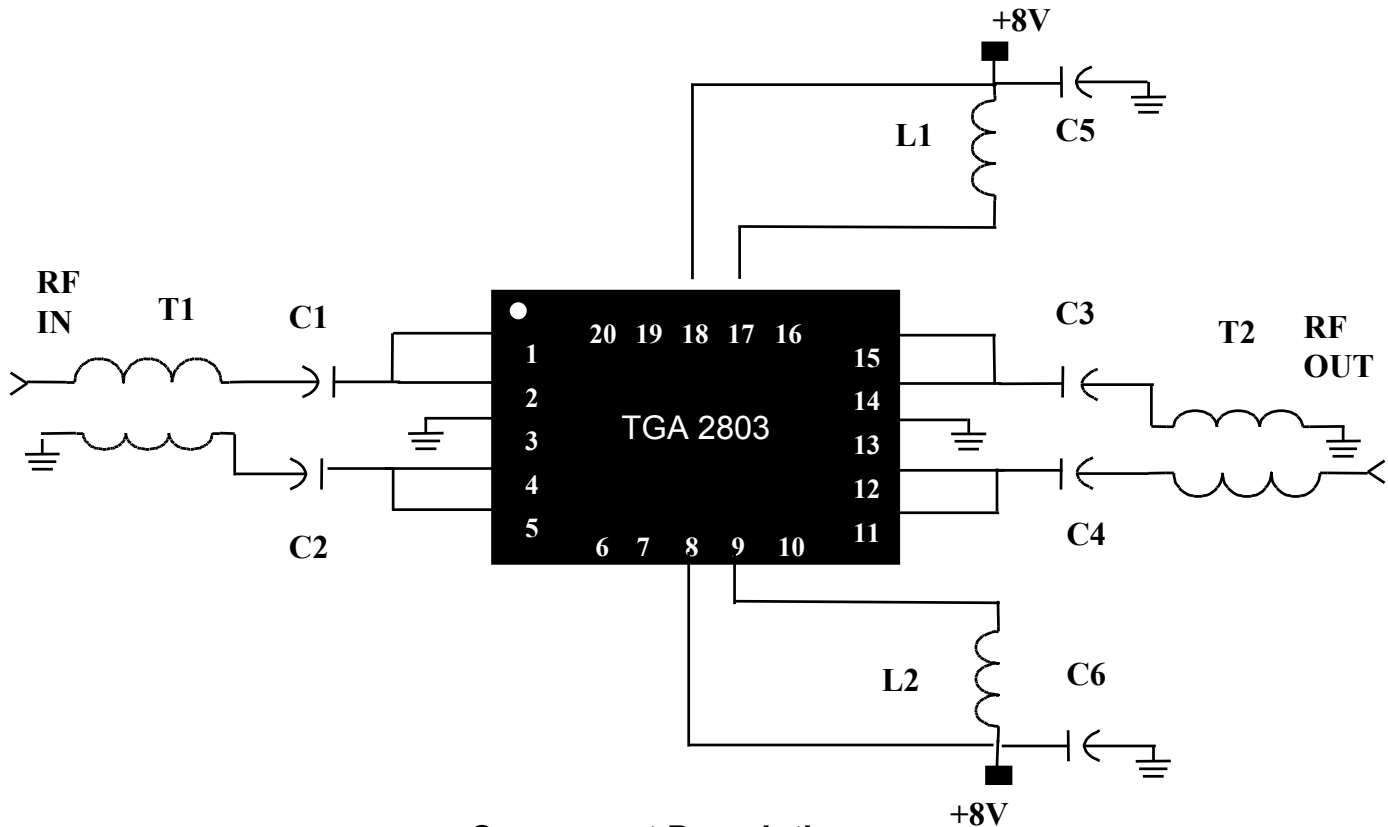


### Optical Receiver





## Recommended Electrical Assembly



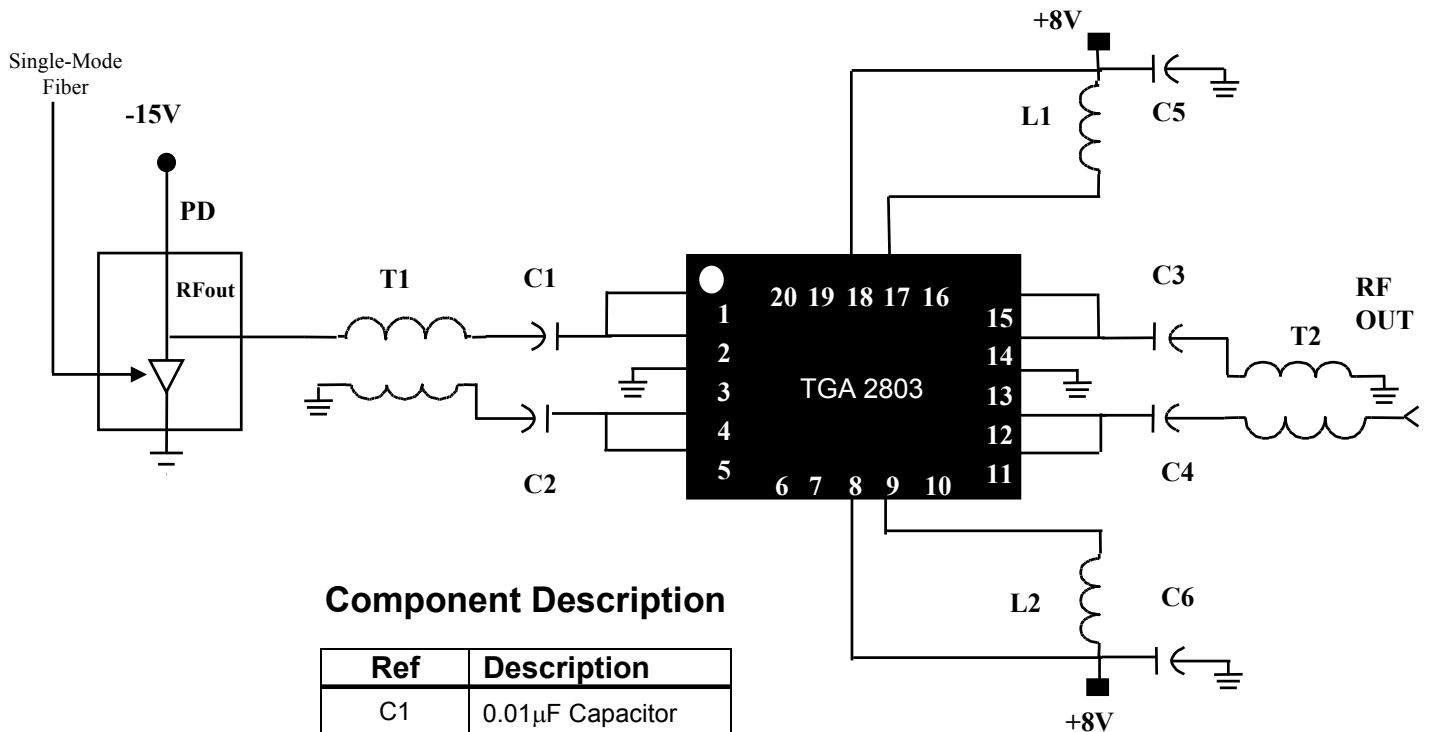
### Component Description

| Ref | Description            |
|-----|------------------------|
| C1  | 0.01 $\mu$ F Capacitor |
| C2  | 0.01 $\mu$ F Capacitor |
| C3  | 470pF Capacitor        |
| C4  | 470pF Capacitor        |
| C5  | 270pF Capacitor        |
| C6  | 270pF Capacitor        |
| L1  | 820nH Inductor         |
| L2  | 820nH Inductor         |
| T1  | Balun <u>1/</u>        |
| T2  | Balun <u>1/</u>        |

1/ Balun performance impacts amplifier return losses and gain. Best performance can be achieved by winding 34 or 36 gauge bifilar wire around a small binocular core made from low-loss magnetic material. Suitable wire may be obtained from MWS Wire Industries. Core vendors include Ferronics, Fairrite, TDK, and Micrometals.

Alternatively, off-the-shelf baluns can be purchased from a number of vendors including Mini-Circuits (ADTL1-18-75), M/A-COM (ETC1-1-13), and Pulse Engineering (CX2071).

## Recommended Electro-Optical Assembly



### Component Description

| Ref | Description                    |
|-----|--------------------------------|
| C1  | 0.01µF Capacitor               |
| C2  | 0.01µF Capacitor               |
| C3  | 470pF Capacitor                |
| C4  | 470pF Capacitor                |
| C5  | 270pF Capacitor                |
| C6  | 270pF Capacitor                |
| L1  | 820nH Inductor                 |
| L2  | 820nH Inductor                 |
| T1  | Balun <u>1/</u>                |
| T2  | Balun <u>1/</u>                |
| PD  | Broadband Photodiode <u>2/</u> |

1/ Balun performance impacts amplifier return losses and gain. Best performance can be achieved by winding 34 or 36 gauge bifilar wire around a small binocular core made from low-loss magnetic material. Suitable wire may be obtained from MWS Wire Industries. Core vendors include Ferronics, Fairrite, TDK, and Micrometals.

Alternatively, off-the-shelf baluns can be purchased from a number of vendors including Mini-Circuits (ADTL1-18-75), M/A-COM (ETC1-1-13), and Pulse Engineering (CX2071).

2/ Emcore 2609C Broadband Photodiode Module is recommended. The module includes a 4:1 impedance transformer.

## Recommended Surface Mount Package Assembly

Proper ESD precautions must be followed while handling packages.

Clean the board with acetone. Rinse with alcohol. Allow the circuit to fully dry.

TriQuint recommends using a conductive solder paste for attachment. Follow solder paste and reflow oven vendors' recommendations when developing a solder reflow profile. Typical solder reflow profiles are listed in the table below.

Hand soldering is not recommended. Solder paste can be applied using a stencil printer or dot placement. The volume of solder paste depends on PCB and component layout and should be well controlled to ensure consistent mechanical and electrical performance.

Clean the assembly with alcohol.

## Typical Solder Reflow Profiles

| Reflow Profile                       | SnPb                        | Pb Free                     |
|--------------------------------------|-----------------------------|-----------------------------|
| Ramp-up Rate                         | 3 °C/sec                    | 3 °C/sec                    |
| Activation Time and Temperature      | 60 – 120 sec @ 140 – 160 °C | 60 – 180 sec @ 150 – 200 °C |
| Time above Melting Point             | 60 – 150 sec                | 60 – 150 sec                |
| Max Peak Temperature                 | 240 °C                      | 260 °C                      |
| Time within 5 °C of Peak Temperature | 10 – 20 sec                 | 10 – 20 sec                 |
| Ramp-down Rate                       | 4 – 6 °C/sec                | 4 – 6 °C/sec                |

## Ordering Information

| Part       | Package Style             |
|------------|---------------------------|
| TGA2803-SM | QFN 20L 4x4 Surface Mount |

***GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.***